

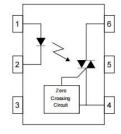
Description

The EL3063S1(TA)-V series of devices each consist of a GaAs infrared emitting diode optically coupled to a monolithic silicon zero voltage crossing photo triac. They are designed for use with a discrete power triac in the interface of logic systems, such as solid-state relays, industrial controls, motors, solenoids and consumer appliances.



Features

- High input-output isolation voltage(Viso = 5,000Vrms)
- High repetitive peak off-state voltage VDRM.
- Min. 600V
- High critical rate of rise of off-state voltage(dv/dt : Min. 1000V/s)
- Operating Temperature: -40℃~110℃
- RoHS



- Pin Configuration
- 1 Anode
- 2 Cathode
- 3 No Connection
- 4 Terminal
- 5 Substrate (do not connect)
- 6 Terminal

Applications

- Solenoid/valve controls
- Static power switch
- AC motor drivers
- Temperature Control

Maximum Ratings

	Parameter	Symbol	Values	Unit
	Forward Current	lF	50	mA
Input	Reverse Voltage	V_R	6	V
	Power Dissipation	Р	120	MW
	Junction Temperature	T_J	125	$^{\circ}$
Output	Off-State Output Terminal Voltage	V _{DRM}	600	V
	Peak Repetitive Surge Current (PW=1ms 120 pps)	Ітѕм	1	А
	On-State RMS Current	I _{T(RMS)}	100	mA
	Junction Temperature	TJ	125	$^{\circ}$ C
	Collector Power Dissipation	Pc	150	mW
Operating temperature range		T_{opr}	40 ~ 110	°C
Storage temperature range		T _{stg}	55 ~ 125	°C
Total Power consumption		P(W)	250	mW
Isolation Voltage ⁽¹⁾		V _{ISO}	5000	Vrms

Notes:

- (1). AC for 1 minute, R.H.= $40 \sim 60\%$ R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.
- (2).For 10 seconds



Electronic Optical Characteristics (TA = 25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditon
Input	Forward Voltage	V _F	-	1.2	1.4	V	I _F =20mA
	Reverse Current	VR	-	-	5	μA	V _R =6V
Output	Peak Blocking Current, Either Direction	IDRM	-	-	500	nA	V _{DRM} = Rated VDRM
	Peak On-State Voltage, Either Direction	V _{TM}	-	-	3	V	I _{тм} = 100mA Peak
	Critical rate of Rise of Off-State Voltage 2	dv/dt	1000	-	-	V/µs	V _{in} =240Vrms
Couple	Led Trigger Current, Current Required to Latch Output,Either Direction	I _{FT}	-	-	15	mA	Main Terminal Voltage = 3V
			-	-	10		
			-	-	5		
	Holding Current, Either Direction	Н	-	400	-	uA	-
ZERO CROSSI NG	Inhibit Voltage	Vinh	-	5	20	Volts	IF=Rated IFT,MT1- MT2 Voltage above which device will not trigger.
	Leakage in Inhibited State	I _{DRM2}	-	-	500	μΑ	$\begin{array}{l} I_{\text{F}}\text{=}\;\text{Rated}\;I_{\text{FT}},\\ \text{Rated}\;V_{\text{DRM}},\\ \text{Off}\;\text{State} \end{array}$

⁽¹⁾ Test voltage must be applied within dv/dt rating.

⁽²⁾ This is static dv/dt. Commutating dv/dt is a function of the load-driving thyristor(s) only.



Characteristics Curves

Fig.1 Forward current vs. Ambient temperature

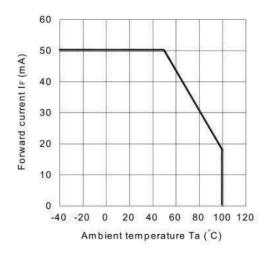


Fig.3 Minimun Trigger Current vs Ambient temperature

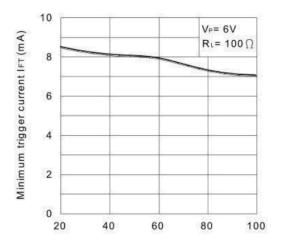


Fig.5 On-state voltage vs Ambient temperature

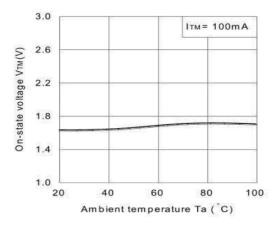


Fig.2 On-state current vs.Ambient temperature

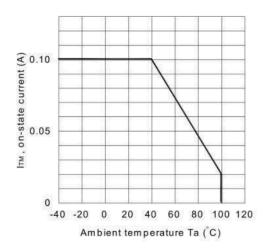


Fig.4 Forward current vs Forward Voltage

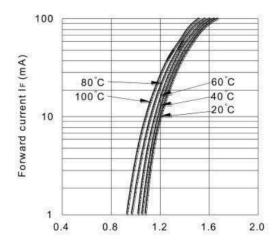


Fig.6 Holding current vs Ambient temperature

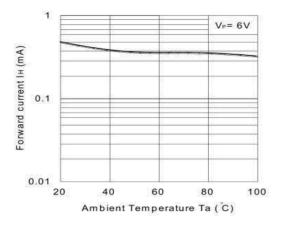


Fig.7 Repetitive peak off-state current vs Temperature

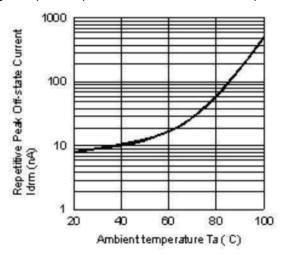


Fig.8 On-state current vs On-state voltage

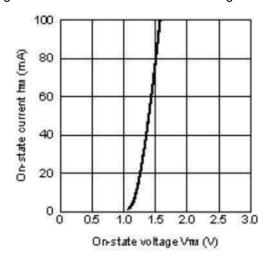


Fig.9 Basic Operation Circuit Medium/High Power Triac Drive Circuit

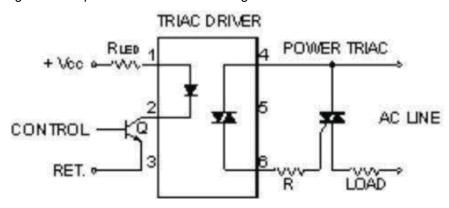
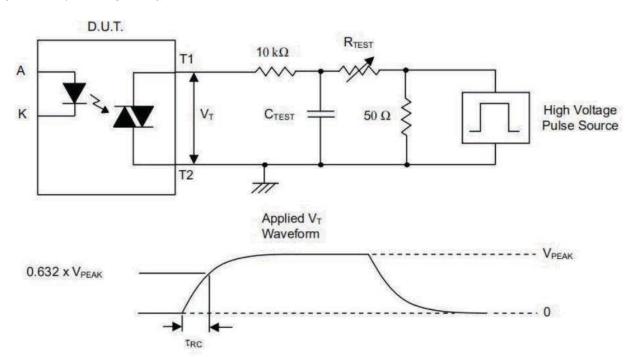
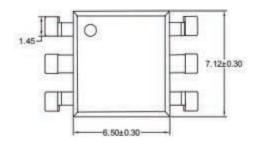


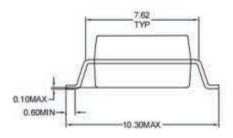
Fig10.Static dv/dt Test Circuit & Waveform

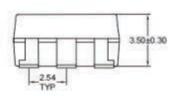


Outline Dimension

SMD-6 Type:



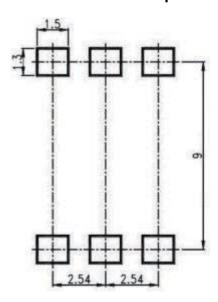




Unit: mm

Tolerance: ±0.1mm

Recommended solder pad Design



Unit: mm

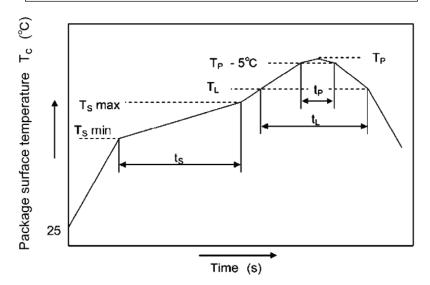
Tolerance: ±0.1mm



Temperature Profile Of Soldering

1. IR Reflow soldering (JEDEC-STD-020D compliant)

Profile item	Conditon
Preheat	
-Temperature Min (TSmin)	150°C
-Temperature Max (TSmax)	200°C
-Time (min to max) (ts)	90 ± 30 sec
Soldering zone	
-Temperature (TL)	217°C
-Time (t∟)	60-150 sec
Peak Temperature (TP)	260°C
-Time (TP-5°C to TP) (ts)	30 sec
Ramp-up rate	3°C / sec max
Ramp-down rate	3~6°C/ sec



Notes:

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.



2. Wave soldering (JEDEC22A111 compliant)

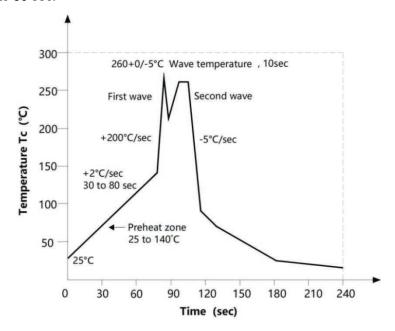
One time soldering is recommended within the condition.

Temperature:260+0/-5°C.

Time:10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.



3. Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature: 380+0/-5°C

Time: 3 sec max.



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